

Refine Search

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Terms	Documents
L7 and (plasma near3 treatment)	5

Database:

US Pre-Grant Publication Full-Text Database
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Search:

L8

Search History

DATE: Thursday, April 14, 2005 [Printable Copy](#) [Create Case](#)

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DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ

<u>L8</u>	L7 and (plasma near3 treatment)	5	<u>L8</u>
<u>L7</u>	L5 and (plasma same amorphous same polysilicon)	28	<u>L7</u>
<u>L6</u>	L5 and plasma	233	<u>L6</u>
<u>L5</u>	L4 and island	273	<u>L5</u>
<u>L4</u>	L3 and amorphous and polysilicon	455	<u>L4</u>
<u>L3</u>	L1 and threshold voltage	770	<u>L3</u>
<u>L2</u>	L1 and threshhold voltage	0	<u>L2</u>
<u>L1</u>	low temperature near8 (thin film transistor or TFT)	2289	<u>L1</u>

END OF SEARCH HISTORY